

7MBR100VN120-50

IGBT MODULE (V series) 1200V / 100A / PIM

Features

Low V_{CE}(sat) Compact Package P.C.Board Mount Module Converter Diode Bridge Dynamic Brake Circuit RoHS compliant product

Applications

Inverter for Motor Drive AC and DC Servo Drive Amplifier Uninterruptible Power Supply



Maximum Ratings and Characteristics

Absolute Maximum Ratings (at Tc=25°C unless otherwise specified)

Items			Symbols	Conditions	Conditions		Units	
	Collector-Emit	ter voltage	Vces				V	
	Gate-Emitter v	oltage	V _{ges}			±20	V	
er				Continuous	Tc=80°C	100		
Inverter	Collector current	Іср	1ms	Tc=80°C	200	А		
		-lc			100	A		
		-lc pulse	1ms	1ms				
	Collector power dissipation		Pc	1 device	1 device		W	
	Collector-Emitter voltage		Vces			1200	V	
	Gate-Emitter voltage		V _{GES}			±20	V	
Brake	Collector current		lc	Continuous	Tc=80°C	75	А	
Bra			Іср	1ms	Tc=80°C	150	A	
	Collector power dissipation		Pc	1 device		385	W	
	Repetitive peak reverse voltage (Diode)		VRRM			1200	V	
er	Repetitive peak reverse voltage		VRRM			1600	V	
Converter	Average output current		lo	50Hz/60Hz, sir	ne wave	100	А	
2nv	Surge current (Non-Repetitive)		IFSM	10ms, Tj=150°C		520	А	
ŏ	I ² t (Non-Repeti	²t (Non-Repetitive)		half sine wave	half sine wave		A ² s	
Junction temperature			Ti Inverter, Brake		175			
Ju	fiction tempera	lture	Tj	Converter	Converter			
Operating junciton temperature (under switching conditions) Case temperature			Inverter, Brake		150	°C		
			Тјор	Converter		150	C	
			Тс					
Storage temperature		Tstg			-40 to +125			
lso	olation voltage	between terminal and copper base (*1) between thermistor and others (*2)	Viso	AC : 1min.		2500	VAC	
Sc	crew torque Mounting (*3)		-	M5	M5		N m	

Note *1: All terminals should be connected together during the test.

Note *2: Two thermistor terminals should be connected together, other terminals should be connected together and shorted to base plate during the test.

Note *3: Recommendable value : 2.5-3.5 Nm (M5)

• Electrical characteristics (at Tj= 25°C unless otherwise specified)

14.0		Symbols	Canditiana		Characteristics			Unite		
τε	ems	Symbols	Conditions	min.	typ.	max.	Units			
	Zero gate voltage collector current	Ices	V _{GE} = 0V, V _{CE} = 1200V		-	-	1.0	mA		
	Gate-Emitter leakage current	Iges	$V_{GE} = 0V, V_{GE} = \pm 20V$		-	-	200	nA		
	Gate-Emitter threshold voltage	V _{GE (th)}	V _{CE} = 20V, I _c = 100mA		6.0	6.5	7.0	V		
	Collector-Emitter saturation voltage	V _{CE (sat)} (terminal)	V _{GE} = 15V I _c = 100A	Tj=25°C	-	2.20	2.65	- V		
				Tj=125°C	-	2.50	-			
				Tj=150°C	-	2.55	-			
		V _{CE (sat)} (chip)	V _{GE} = 15V I _c = 100A	Tj=25°C	-	1.75	2.20			
				Tj=125°C	-	2.05	-			
				Tj=150°C	-	2.10	-			
	Input capacitance	Cies	V _{CE} = 10V, V _{GE} = 0V, f = 1MHz		-	9.1	-	nF		
el le	Turn-on time	ton			-	0.39	1.20			
nverter		tr	$V_{cc} = 600V$		-	0.09	0.60	μs		
-		tr (i)	Ic = 100A Vge = +15 / -15V		-	0.03	-			
	Turn-off time	toff	$R_{\rm G} = 1.6\Omega$		-	0.53	1.00			
		tf			-	0.06	0.30			
	Forward on voltage	V _F (terminal)	I _F = 100A	Tj=25°C	-	2.15	2.60	- V		
				Tj=125°C	-	2.30	-			
				Tj=150°C	-	2.25	-			
		V _F (chip)	I _F = 100A	Tj=25°C	-	1.70	2.15			
				Tj=125°C	-	1.85	-	1		
				Tj=150°C	-	1.80	-]		
	Reverse recovery time	trr IF = 100A		-	-	0.1	μs			
	Zero gate voltage collector current	Ices	V _{GE} = 0V V _{CE} = 1200V		-	-	1.0	mA		
	Gate-Emitter leakage current	Iges	V _{CE} = 0V V _{GE} = +20 / -20V		-	-	200	nA		
	Collector-Emitter saturation voltage	V _{CE (sat)} (terminal)	V _{GE} = 15V	Tj=25°C	-	2.20	2.65	- V		
				Tj=125°C	-	2.55	-			
			Ic = 75A	Tj=150°C	-	2.60	-			
		V _{CE (sat)} (chip)	V _{GE} = 15V Ic = 75A	Tj=25°C	-	1.85	2.30			
				Tj=125°C	-	2.20	-			
				Tj=150°C	-	2.25	-			
		ton	$y_{1} = 000y_{1}$		-	0.39	1.20			
	Turn-on time	tr	V _{CE} = 600V Ic = 75A		-	0.09	0.60			
		toff	V _{GE} = +15 / -15V		-	0.53	1.00	μs		
	Turn-off time	tf	$R_{G} = 2.2\Omega$		-	0.06	0.30			
	Reverse current IRRM V _R = 1200V			-	-	1.00	mA			
D	E	V _{FM} (chip)	I _F = 100A	terminal	-	1.95	2.40			
Converte	Forward on voltage Reverse current			chip	-	1.50	-	- V		
	Reverse current	IRRM	V _R = 1600V		-	-	1.0	mA		
		R	T = 25°C		- 5000		-	Ω		
	Resistance		T = 100°C	465	495	520				
I nermistor	B value	В	T = 25 / 50°C		3305	3375	3450	K		

• Thermal resistance characteristics

láoma	Symbolo	Conditions	Characteristics			Units
Items	Symbols	Conditions	min.	typ.	max.	Units
Fhermal resistance (1device)	Rth(j-c)	Inverter IGBT	-	-	0.29	°C/W
		Inverter FWD	-	-	0.44	
		Brake IGBT	-	-	0.39	
		Converter Diode	-	-	0.43	
Contact thermal resistance (1device) (*4) Rth(c-f)		with Thermal Compound	-	0.05	-]

Note *4: This is the value which is defined mounting on the additional cooling fin with thermal compound.

Characteristics (Representative)



Collector - Emitter voltage: V_{CE} [V]











Transient thermal resistance (max.)





[Thermistor] Temperature characteristic (typ.)







[Brake]





[Brake] Dynamic gate charge (typ.) Vcc=600V, Ic=100A, Tj= 25°C



Outline Drawings, mm



Section A-A

Equivalent Circuit Schematic



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